

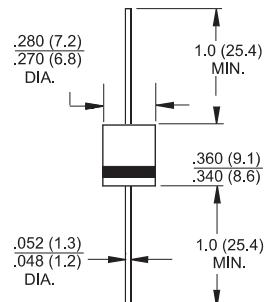


Features

- ✧ Glass passivated chip junction.
- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260 °C /10 seconds/.375",(9.5mm) lead lengths at 5 lbs.,(2.3kg) tension
- ✧ Weight: 1.65 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	6A 05G	6A 10G	6A 20G	6A 40G	6A 60G	6A 80G	6A 100G	Units		
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V		
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V		
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V		
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length @ $T_A = 50^\circ C$	$I_{(AV)}$	6.0							A		
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	250							A		
Maximum Instantaneous Forward Voltage @6.0A	V_F	1.1		1.0							
Maximum DC Reverse Current @ $T_A=25^\circ C$ at Rated DC Blocking Voltage @ $T_A=125^\circ C$	I_R	10 100							uA uA		
Typical Junction Capacitance (Note 1)	C_J	60							pF		
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	35							°C/W		
Operating and Storage Temperature Range	T_J, T_{STG}	- 65 to + 150							°C		

Notes: 1. Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.

2. Mount on Cu-Pad Size 16mm x 16mm on P.C.B.

RATINGS AND CHARACTERISTIC CURVES (6A05G THRU 6A100G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

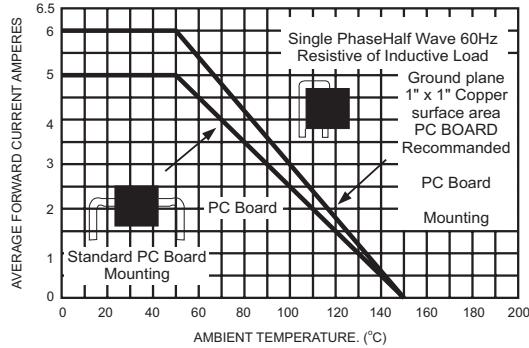


FIG.2- TYPICAL REVERSE CHARACTERISTICS PER LEG

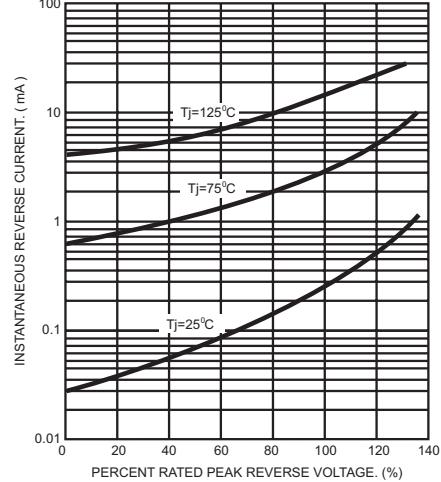


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

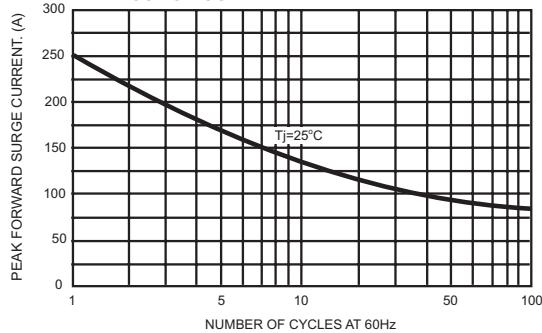


FIG.4- TYPICAL JUNCTION CAPACITANCE

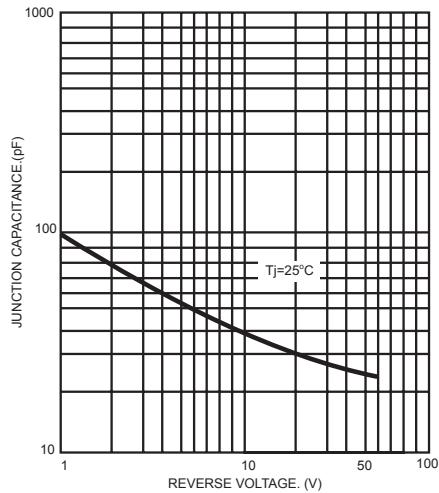
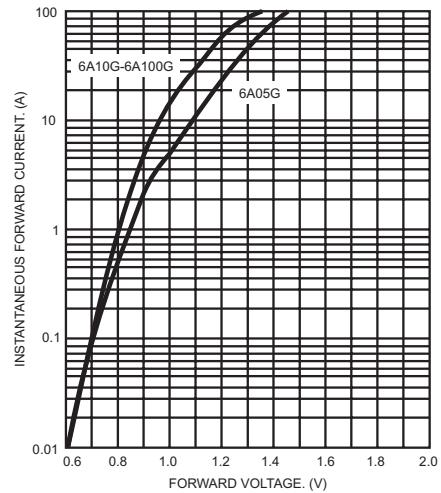


FIG.5- TYPICAL FORWARD CHARACTERISTICS



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